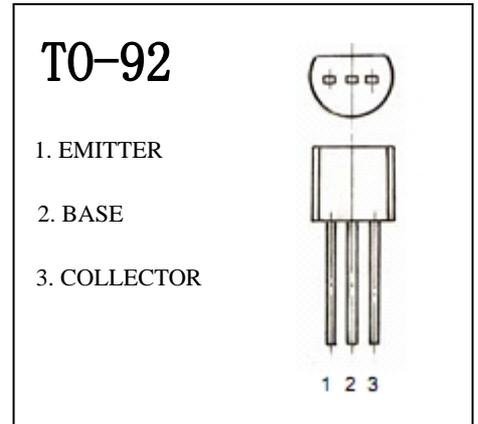




D471A TRANSISTOR(NPN)

MAXIMUM RATINGS(Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Units
VCBO	Collector-Base Voltage	40	V
VCEO	Collector-Emitter Voltage	30	V
VEBO	Emitter-Base Voltage	5	V
IC	Collector Current	1.0	A
PC	Collector Power Dissipation	800	mW
Tj	Junction Temperature	150	°C
Tstg	Storage Temperature	-55~150	°C



ELECTRICAL CHARACTERISTICS(Tamb=25°C unless otherwise specified):

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	V(BR)CBO	IC=100uA, IE=0	40			V
Collector-emitter breakdown voltage	V(BR)CEO	IC=1mA, IB=0	30			V
Emitter-base breakdown voltage	V(BR)EBO	IC=100uA, IC=0	5			V
Collector cut-off current	ICBO	VCB=30V, IE=0			0.1	μA
Emitter cut-off current	IEBO	VEB=5V, IC=0			0.1	μA
DC current gain	HFE	Vce=1V, Ic=100mA	70		400	
Collector-emitter saturation voltage	VCE(sat)	IC=1.0A,IB=0.1A			0.5	V
Base-emitter saturation voltage	VBE(sat)	IC=1.0A,IB=0.1A			1.2	V
Transition Frequency	fT	VCE=6V,IC=10mA		130		MHZ
Collector output capacitance	Cob	VCB=6V,IE=0,f=1MHz		16		pF